

L Number	Hits	Search Text	DB	Time stamp
-	7	high adj voltage adj protection adj diode	USPAT; US-PGPUB	2003/02/13 15:11
-	234	epitaxial adj layer adj formed adj substrate	USPAT; US-PGPUB	2003/02/13 14:43
-	19	substrate adj formed adj epitaxial adj layer	USPAT; US-PGPUB	2003/02/13 14:46
-	7	substrate adj deposited adj epitaxial adj layer	USPAT; US-PGPUB	2003/02/13 14:46
-	162	(high adj voltage) same (protection adj diode)	USPAT; US-PGPUB	2003/02/13 14:51
-	314	257/\$.ccls. and (protection adj diode)	USPAT; US-PGPUB	2003/02/13 14:58
-	82	438/\$.ccls. and (protection adj diode)	USPAT; US-PGPUB	2003/02/13 14:58
-	685	high adj voltage adj diode	USPAT; US-PGPUB	2003/02/13 15:12